

TSU111, TSZ182 op amps & P-NUCLEO-IKA02A1

January 31st, 2023



Agenda



ST's family of zero-drift amplifiers Technology and device parameters





Our family of chopper amplifiers

Best in precision, large input and output operating range

TSZ121

TSZ122

TSZ124

TSZ182

TSZ181

TSU111

TSU112

TSU114

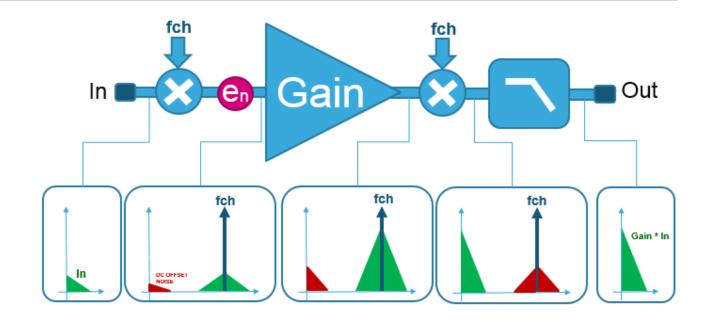
1000 factor gain!

Op amp type	Standard commodity	Precision	Chopper TSZ
Input offset voltage	5 mV	400 μV	5 μV
Offset drift	30 μV/°C	1 μV/°C	30 nV/°C
1/f noise	High	Medium	No
Input and output range	Limited	Full	range
			No I range AUTOMOTIVE GRADE





Frequency domain explanation

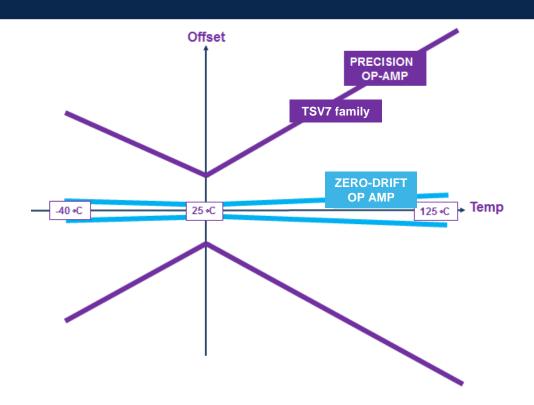


The **input signal** faces one **modulation** and one **demodulation**. The DC **errors** (offset and (1/f) noise) face one **demodulation only**, resulting in permanent amplifier **imperfection cancellation**.





Zero-drift op amps really don't drift

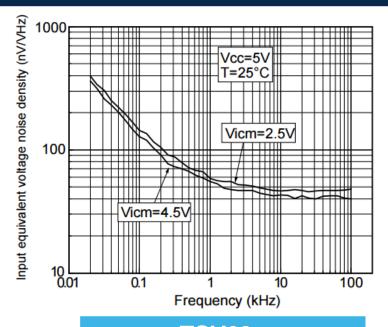


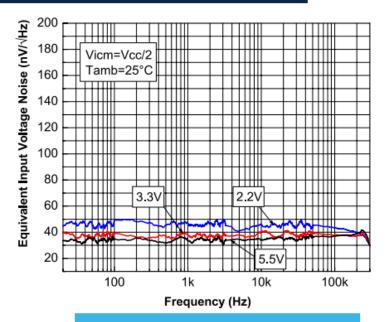
Input offset voltage imperfection changes with temperature, however as a DC error it is canceled.





1/f noise has disappeared





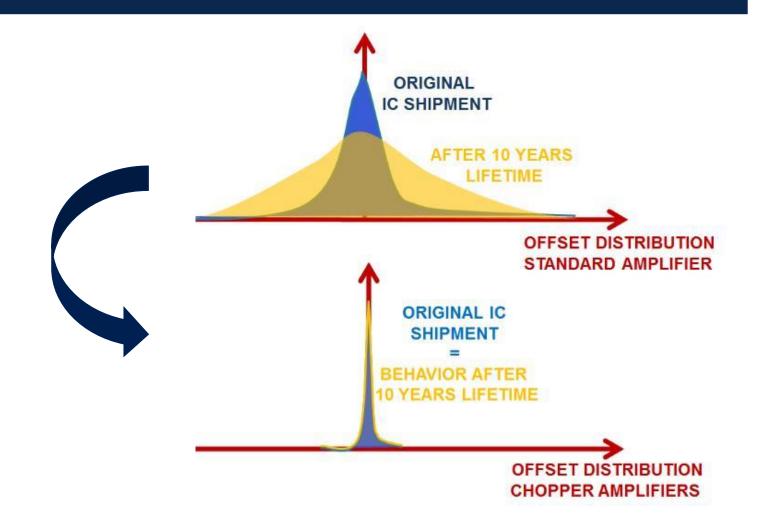
TSV63x general purpose CMOS op amp TSZ18x
Chopper CMOS op amp

1/f noise increases with lower frequencies making standard CMOS op amps less precise in very slow applications. This noise disappears in chopper architecture thanks to modulation.





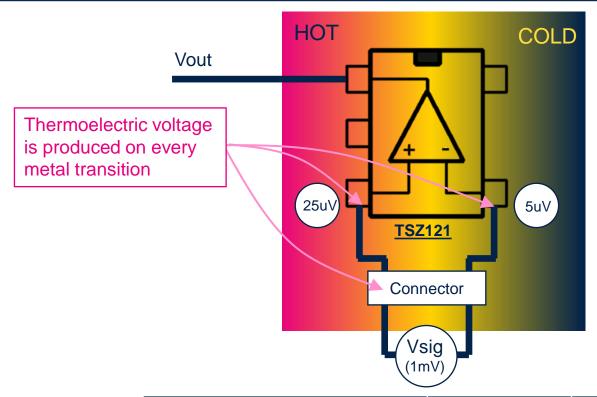
Stays young forever







Heat can destroy your precision



Every metal transition produces tiny voltage. If there is some temperature gradient on the device the voltages differ and the op amp cannot distinguish this from real signal.



Temperature	Input signal	Impact of Vio	Impact of Vterm	Error
Stabilized (no difference)	1 mV	5 μV	0 μV	0.5%
Temp gradient (big difference)	1 mV	5 μV	20 μV	2.5%

Recently featured zero-drift amplifiers: TSU111 and TSZ181



TSZ181, TSZ182, TSZ181H, TSZ182H, TSZ182H1

Very high accuracy for very high temperature

- Very high accuracy and stability:
 - 25 μV max. at 25°C
 - 35 μV -40°C to 125°C
 - 44 μV max. at 150°C
 - 65 μV max. at 175°C
- Gain bandwidth product: 3 MHz
- Rail-to-rail input and output
- Low supply voltage: 2.2–5.5 V
- High slew rate: 4.7 V/µs







Exhaust & emission control





TSZ181HY, **TSZ182HY**

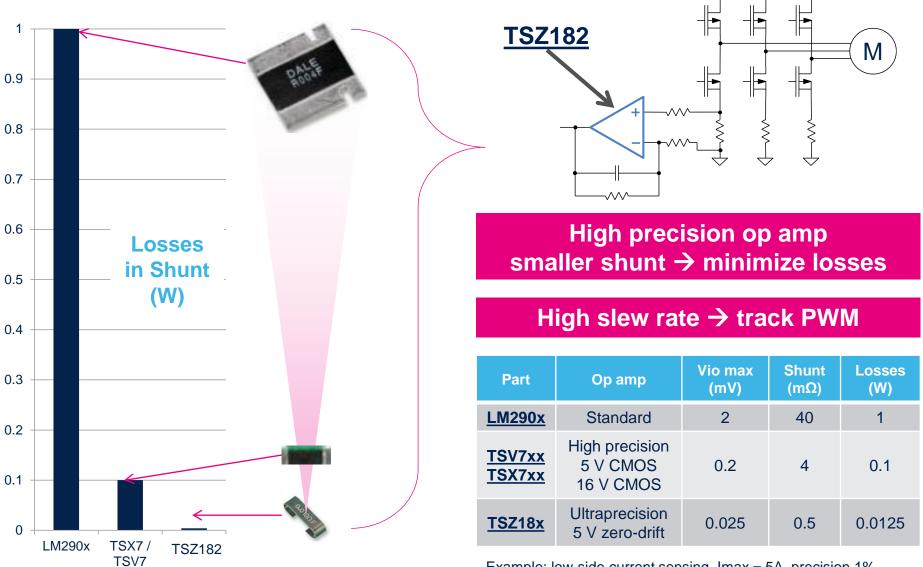
High temperature operating **up to 150°C**

TSZ182H1Y High temperature operating up to 175°C



Accuracy virtually unaffected by temperature change

BLDC motor control

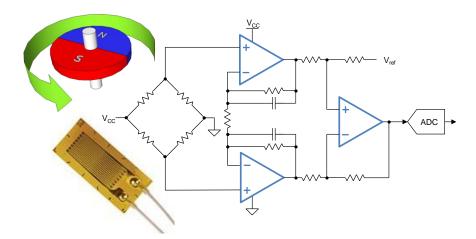




High-speed instrumentation amplifier

High speed signal conditioning from sensors in Wheatstone bridge

- AMR magnetic sensors → dynamic magnetic field around motor, wire.
- Strain gauges → dynamic mechanical constrains.



High precision op amp Better accuracy → more bits

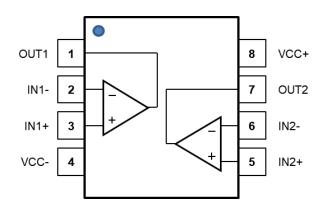
High GBW→ dynamic signals

	Vio max	Max offset at ADC with gain of 100 (Vio impact 202x)	Equivalent Effective ADC bits
TSZ182	25 μV	5.05 mV	~10 bits
<u>TS507</u>	100 μV	20.2 mV	~8 bits
TS512A	500 μV	101 mV	~6 bits
TS512	2.5 mV	505 mV	~3 bits



TSU111, TSU112, TSU114

Nano-power precision amplifier



Benefits

- Suitable for always on applications
- High accuracy without calibration
- Running more than 25 years on CR2032 coin cell battery

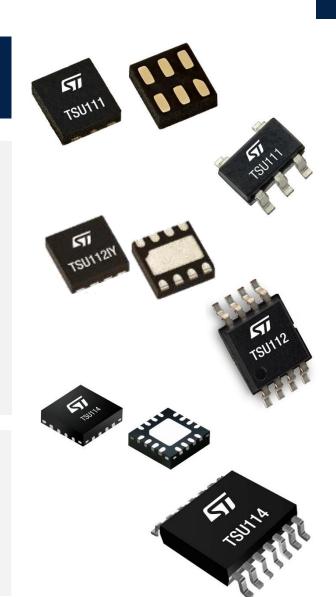


Key Features

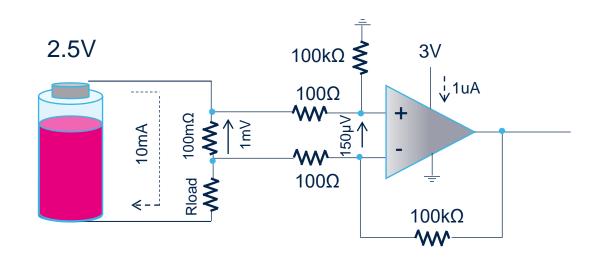
- Sub-microampere current consumption:
 - Icc = 900 nA typ. at 25°C
- Low offset voltage:
 - 150 μV max. at 25°C
 - 235 μV max. -40 to 125°C
- Low noise over 0.1 to 10 Hz: 3.6 μVpp
- Low supply voltage: 1.5 V to 5.5 V
- Gain bandwidth product: 11.5 kHz typ

Target applications

- Car access
- Alarm and anti-theft
- Telematic boxes
- Surrounding monitoring



Current sensing in battery-powered applications



	Vio max	Supply current	Impact on application
<u>TSU111</u>	150 µV	1 μΑ	0.01%
<u>TSV711</u>	200 μV	14 μΑ	0.14%
TS507	100 μV	1 mA	10%

Example: Op amps with similar V_{IO} selected

Ideal for wearables

Battery current sensing for SOC estimate



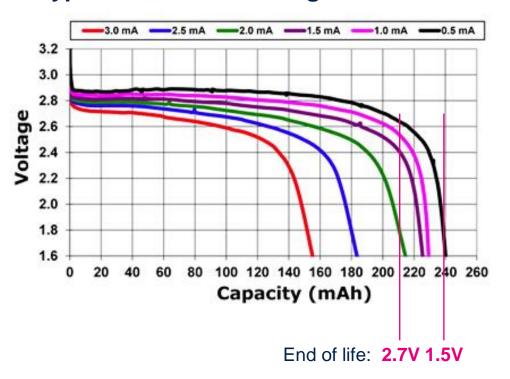
High precision op amp Better accuracy → more bits

Low power consumption → longer battery lifetime



Works from very low voltage

Typical CR2032 discharge characteristic



Most op amps can
work down to 2.7 V
or 2.5 V
TSU111 can work
with 1.5 V → get all
the power from the
battery

>10% remains @ 500 µA load

Note: Even in applications that consume 10 μ A or less, this op amp can help extend battery lifetime by weeks or months.



P-NUCLEO-IKA02A1 STM32 Nucleo electrochemical toxic gas sensor expansion board with CO sensor



Electrochemical gas sensor expansion board



P-NUCLEO-IKA02A1 hardware description

- The P-NUCLEO-IKA02A1 is an electrochemical gas sensor evaluation board.
- It embeds several footprints to host different types of sensors and different target gases.
- The connectivity is assured thanks to Arduino UNO R3 connector and ST morpho connector layout.



Key products on board

TSU111

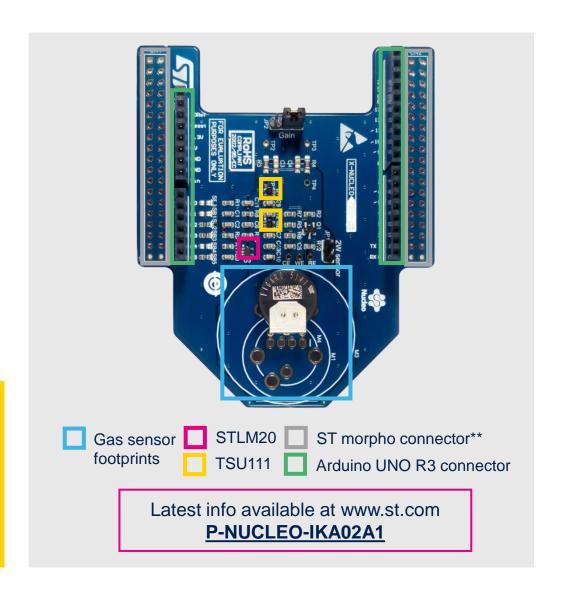
Nanopower (900 nA), high accuracy (150 µV) 5 V op amp.

STLM20

Ultra-low current 2.4 V precision analog temperature sensor.

Gas sensor

4 different footprints for various electrochemical gas sensors (PCD 13.5 mm, PCD 17 mm, miniature, TGS5141).





Working principle of electrochemical sensors



Membrane allows gas to pass through and react with electrode

 More different compounds can pass through membrane and causes cross sensitivity (filter can be used).

Electrolyte evaporate through membrane – limited lifetime (the more sensitive the shorter lifetime).

Oxidation or reduction of target gas

- Small amount of oxygen needed.
- Electrons cannot pass through electrolyte so it must go around and the positive or negative current is generated.

2 or 3 electrodes acting as a catalyst

3 electrode sensors may need bias voltage to be applied.

If no current can flow sensor will polarize

 $\begin{array}{c} {\rm CO,\,CO_{2,}\,O_{2},\,O_{3},\,NO_{x},\,H_{2}S,\,H_{2},\,Cl_{2},} \\ {\rm ClO_{2},\,C_{x}H_{x},\,NH_{3},\,SO_{2}} \end{array}$

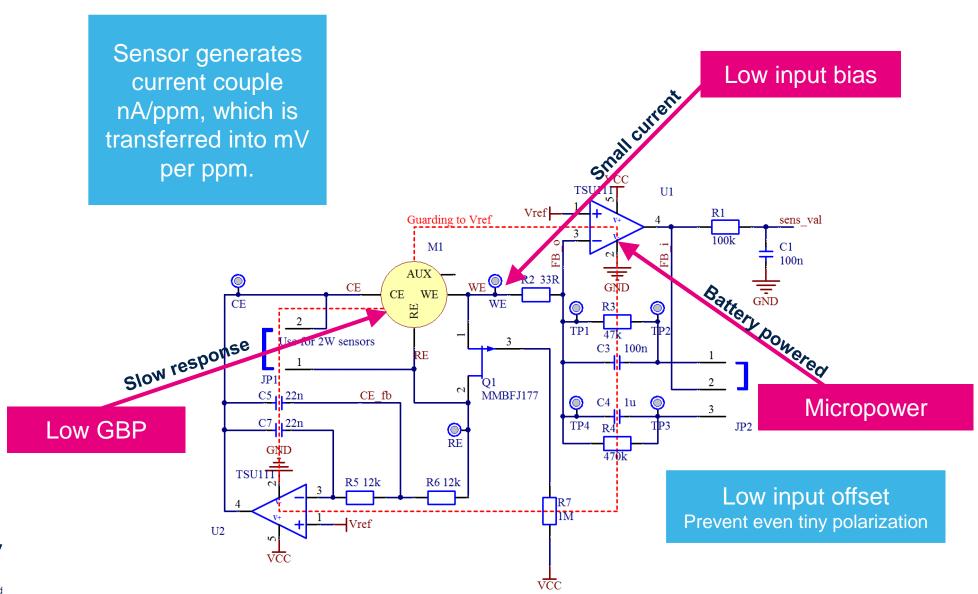
Electrolyte

Gas membrane

RE

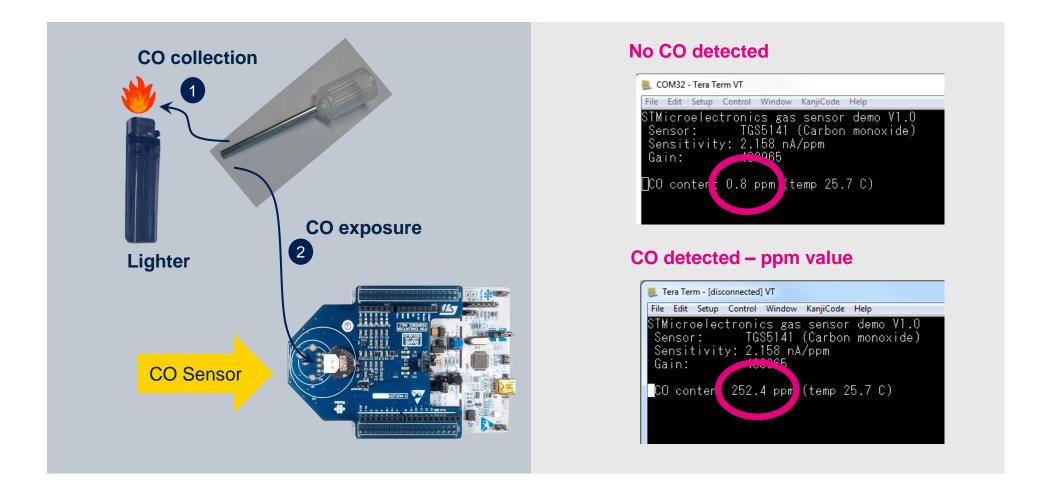
H₂O 2H+

P-NUCLEO-IKA02A1 application schematic



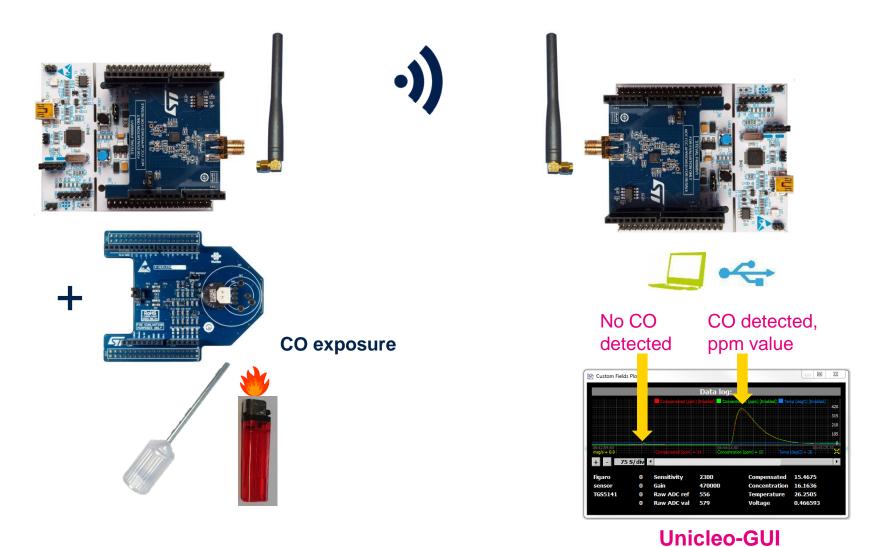


X-CUBE-IKA02A1 example using serial line monitor





Wireless home carbon monoxide detector demo





Our technology starts with You



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